

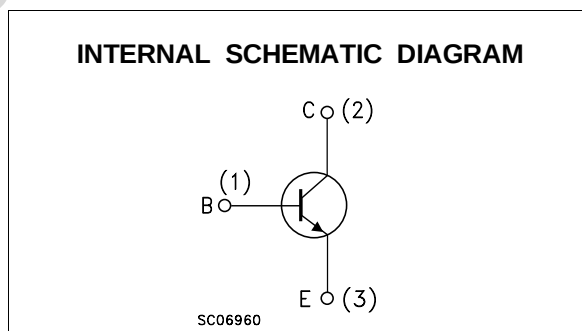
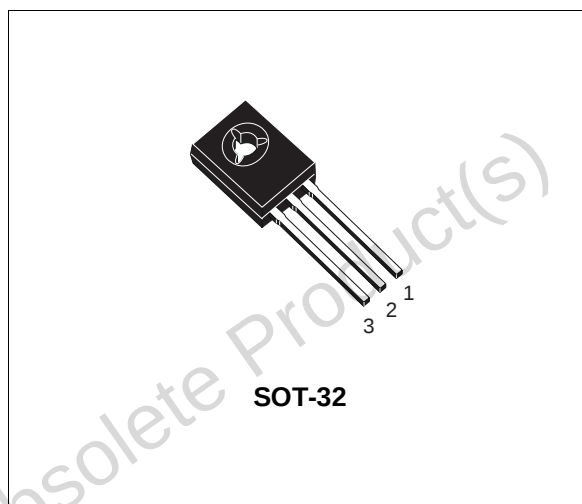
SILICON NPN TRANSISTOR

- STMicroelectronics PREFERRED SALESTYPE

DESCRIPTION

The MJE521 is a silicon Epitaxial-Base NPN transistor in Jedec SOT-32 plastic package.

It is intended for use in 5 to 20W audio amplifiers, general purpose amplifier and switching circuits.



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage ($I_E = 0$)	40	V
V_{CEO}	Collector-Emitter Voltage ($I_B = 0$)	40	V
V_{EBO}	Emitter-Base Voltage ($I_C = 0$)	4	V
I_C	Collector Current	4	A
I_{CM}	Collector Peak Current ($t_p < 5$ ms)	8	A
I_B	Base Current	2	A
P_{tot}	Total Dissipation at $T_c \leq 25$ °C	40	W
T_{stg}	Storage Temperature	-65 to 150	°C
T_j	Max. Operating Junction Temperature	150	°C

MJE521

THERMAL DATA

$R_{thj-amb}$	Thermal Resistance Junction-ambient	Max	3.12	$^{\circ}\text{C}/\text{W}$
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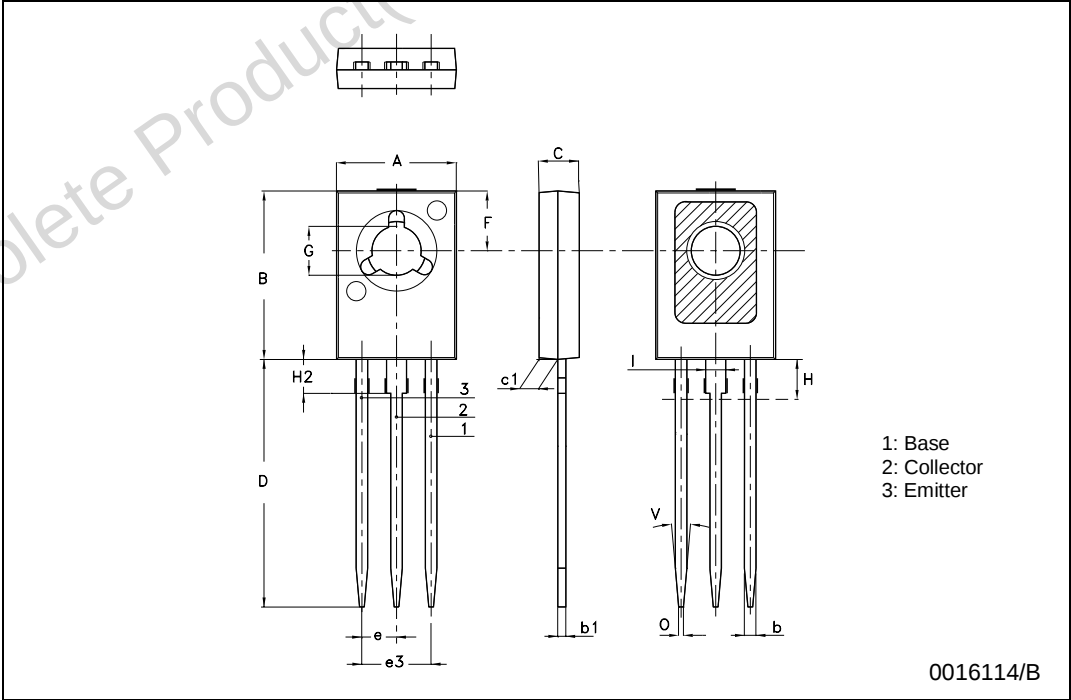
ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector Cut-off Current ($I_E = 0$)	$V_{CB} = 40\text{ V}$			100	μA
I_{EBO}	Emitter Cut-off Current ($I_C = 0$)	$V_{EB} = 4\text{ V}$			100	μA
$V_{CEO(sus)}^*$	Collector-Emitter Sustaining Voltage ($I_B = 0$)	$I_C = 0.1\text{ A}$	40			V
h_{FE}	DC Current Gain	$I_C = 1\text{ A}$ $V_{CE} = 1\text{ V}$	40			

* Pulsed: Pulse duration = 300 μs , duty cycle $\leq 1.5\%$

SOT-32 (TO-126) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	7.4		7.8	0.291		0.307
B	10.5		10.8	0.413		0.425
b	0.7		0.9	0.028		0.035
b1	0.40		0.65	0.015		0.025
C	2.4		2.7	0.094		0.106
c1	1.0		1.3	0.039		0.051
D	15.4		16.0	0.606		0.630
e		2.2			0.087	
e3		4.4			0.173	
F		3.8			0.150	
G	3		3.2	0.118		0.126
H			2.54			0.100
H2		2.15			0.084	
I		1.27			0.05	
O		0.3			0.011	
V		10 ⁰			10 ⁰	



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